

Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

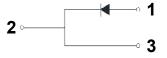
- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives





Part Number	Package	Qty(PCS)	
HFFSP1065B	TO-220C-2L	50	







Maximum Ratings ($T_c = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	650	٧		
V _{RSM}	Surge Peak Reverse Voltage	650	٧		
V _{DC}	DC Blocking Voltage	650	٧		
I _F	Continuous Forward Current	30 14.5 10	А	T _c =25°C T _c =135°C T _c =153°C	Fig. 3
I _{FRM}	Repetitive Peak Forward Surge Current	46 31	Α	T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =110°C, t_p =10 ms, Half Sine Wave	
I _{FSM}	Non-Repetitive Peak Forward Surge Current	90 71	Α	T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =110°C, t_p = 10 ms, Half Sine Wave	Fig. 8
I _{F,Max}	Non-Repetitive Peak Forward Surge Current	860 680	А	$T_c = 25^{\circ}C$, $t_p = 10 \mu s$, Pulse $T_c = 110^{\circ}C$, $t_p = 10 \mu s$, Pulse	Fig. 8
P _{tot}	Power Dissipation	136.5 59	W	T _c =25°C T _c =110°C	Fig. 4
T_{J} , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	



Electrical Characteristics

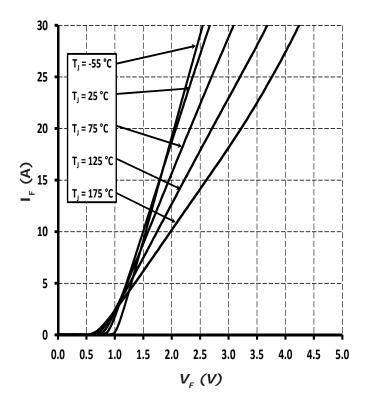
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.5 2.0	1.8 2.4	V	I _F = 10 A T _J =25°C I _F = 10 A T _J =175°C	Fig. 1
I _R	Reverse Current	12 24	60 220	μΑ	V _R = 650 V T _J =25°C V _R = 650 V T _J =175°C	Fig. 2
Q _c	Total Capacitive Charge	24		nC	$V_R = 400 \text{ V, } I_F = 10 \text{ A}$ $di/dt = 500 \text{ A/}\mu\text{s}$ $T_J = 25^{\circ}\text{C}$	Fig. 5
С	Total Capacitance	460.5 44 40		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 200 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz	Fig. 6
E _c	Capacitance Stored Energy	3.6		μJ	V _R = 400 V	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

S	ymbol	Parameter	Тур.	Unit	Note
	$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.1	°C/W	Fig. 9

Typical Performance





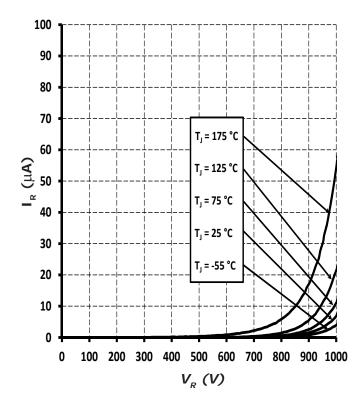
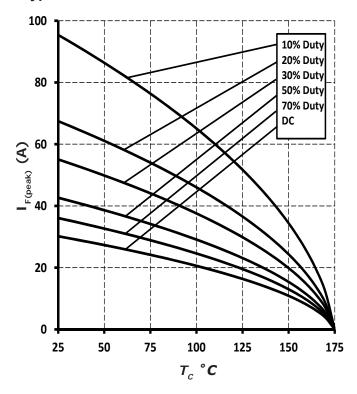
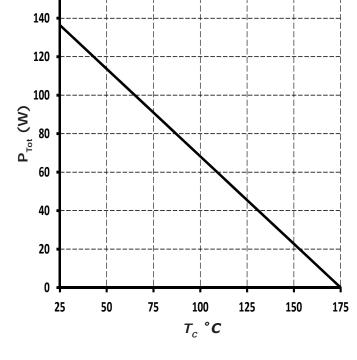


Figure 2. Reverse Characteristics



Typical Performance





160

Figure 3. Current Derating

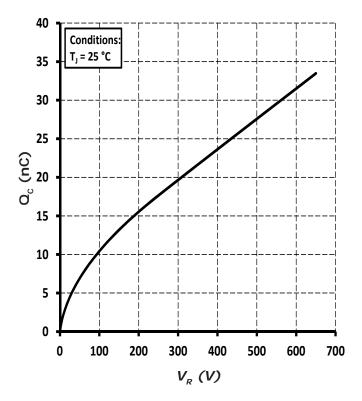


Figure 5. Total Capacitance Charge vs. Reverse Voltage

Figure 4. Power Derating

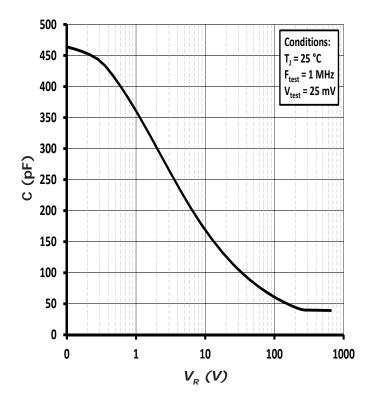
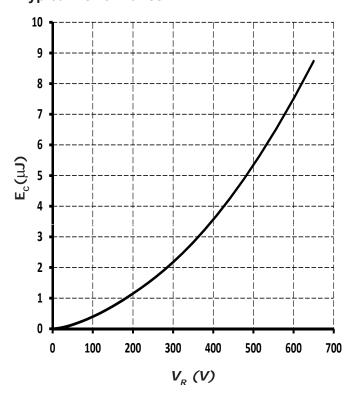
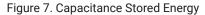


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance





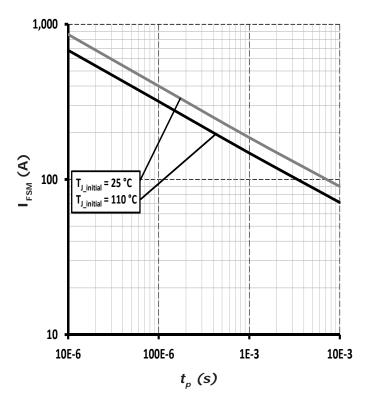


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

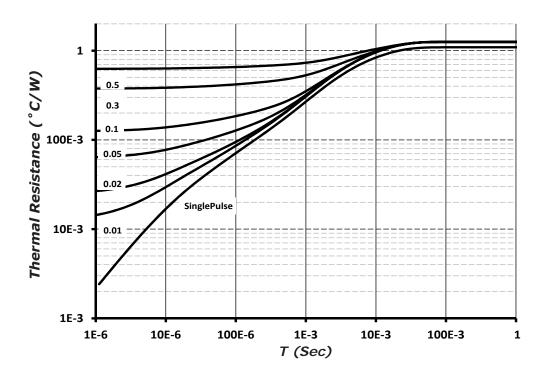


Figure 9. Transient Thermal Impedance

Diode Model

$$\begin{array}{c|c} - & & \\ \hline V_T & R_T \end{array}$$

$$Vf_T = V_T + If * R_T$$

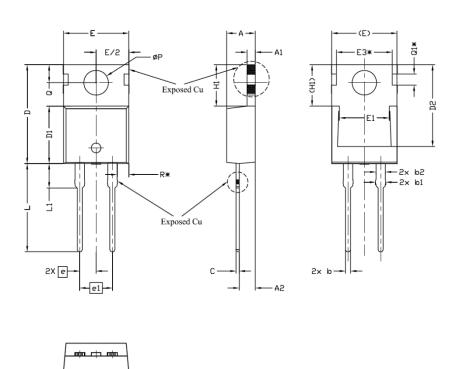
$$V_T = 0.94 + (T_J^* - 1.3^* 10^{-3})$$

 $R_T = 0.044 + (T_J^* 4.4^* 10^{-4})$

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

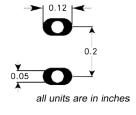


Package Information TO-220C-2L

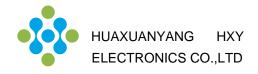


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SYMBOL	MIN.	NOM.	NOTES	
А	4,24	4.44	4,64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
þ	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.20 1.45		
С	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.43	12.73	12.83	5
E	9.96	10.16	10.36	4,5
E1	6,86	7.77	8,89	5
E3*				
е				
e1				
H1	6.30	6.45	6.60	5,6
L	13,47	13.72	13.97	
L1	3.60	3.80	4.00	
ØP	3.75	3.84	3.93	
Q	2,60 2,80		3,00	
Q1*				
R*				

Recommended Solder Pad Layout



T0220-2L



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